

74ALVCH16374

Low-Voltage 16-Bit D-Type Flip-Flop with Bus Hold 1.8/2.5/3.3 V (3-State, Non-Inverting)

The 74ALVCH16374 is an advanced performance, non-inverting 16-bit D-type flip-flop. It is designed for very high-speed, very low-power operation in 1.8 V, 2.5 V or 3.3 V systems. The VCXH16374 is byte controlled, with each byte functioning identically, but independently. Each byte has separate Output Enable and Clock Pulse inputs. These control pins can be tied together for full 16-bit operation.

The 74ALVCH16374 consists of 16 edge-triggered flip-flops with individual D-type inputs and 3.6 V-tolerant 3-state outputs. The clocks (CPn) and Output Enables ($\overline{OE}n$) are common to all flip-flops within the respective byte. The flip-flops will store the state of individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the $\overline{OE}$ LOW, the contents of the flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. The $\overline{OE}$ input level does not affect the operation of the flip-flops. The data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating inputs at a valid logic state.

- Designed for Low Voltage Operation: $V_{CC} = 1.65 - 3.6$ V
- 3.6 V Tolerant Inputs and Outputs
- High Speed Operation: 3.6 ns max for 3.0 to 3.6 V
4.5 ns max for 2.3 to 2.7 V
7.8 ns max for 1.65 to 1.95 V
- Static Drive: ± 24 mA Drive at 3.0 V
 ± 12 mA Drive at 2.3 V
 ± 4 mA Drive at 1.65 V
- Supports Live Insertion and Withdrawal
- Includes Active Bushold to Hold Unused or Floating Inputs at a Valid Logic State
- I_{OFF} Specification Guarantees High Impedance When $V_{CC} = 0$ V[†]
- Near Zero Static Supply Current in All Three Logic States (40 μ A)
Substantially Reduces System Power Requirements
- Latchup Performance Exceeds ± 250 mA @ 125°C
- ESD Performance: Human Body Model >2000V; Machine Model >200V
- Second Source to Industry Standard 74ALVCH16374

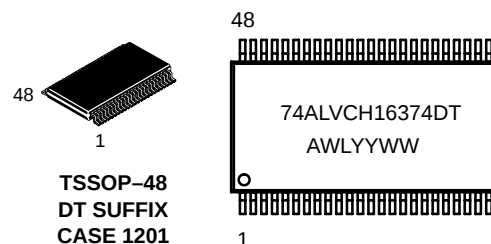
[†]To ensure the outputs activate in the 3-state condition, the output enable pins should be connected to V_{CC} through a pull-up resistor. The value of the resistor is determined by the current sinking capability of the output connected to the $\overline{OE}$ pin.



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MARKING DIAGRAM



A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week

PIN NAMES

Pins	Function
$\overline{OE}n$	Output Enable Inputs
CPn	Clock Pulse Inputs
D0-D15	Inputs
O0-O15	Outputs

ORDERING INFORMATION

Device	Package	Shipping
74ALVCH16374DTR	TSSOP	2500 / Reel

74ALVCH16374

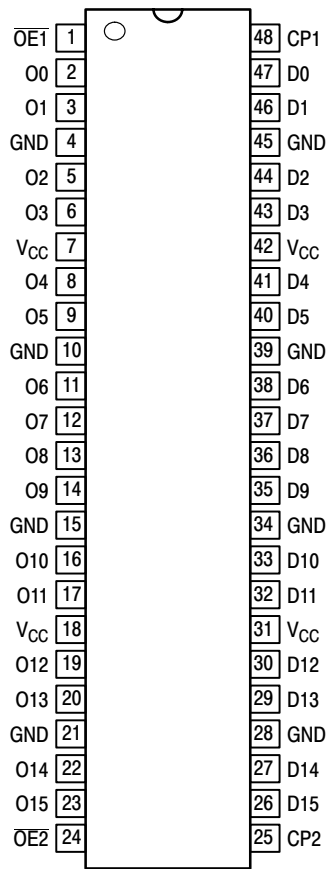


Figure 1. 48-Lead Pinout
(Top View)

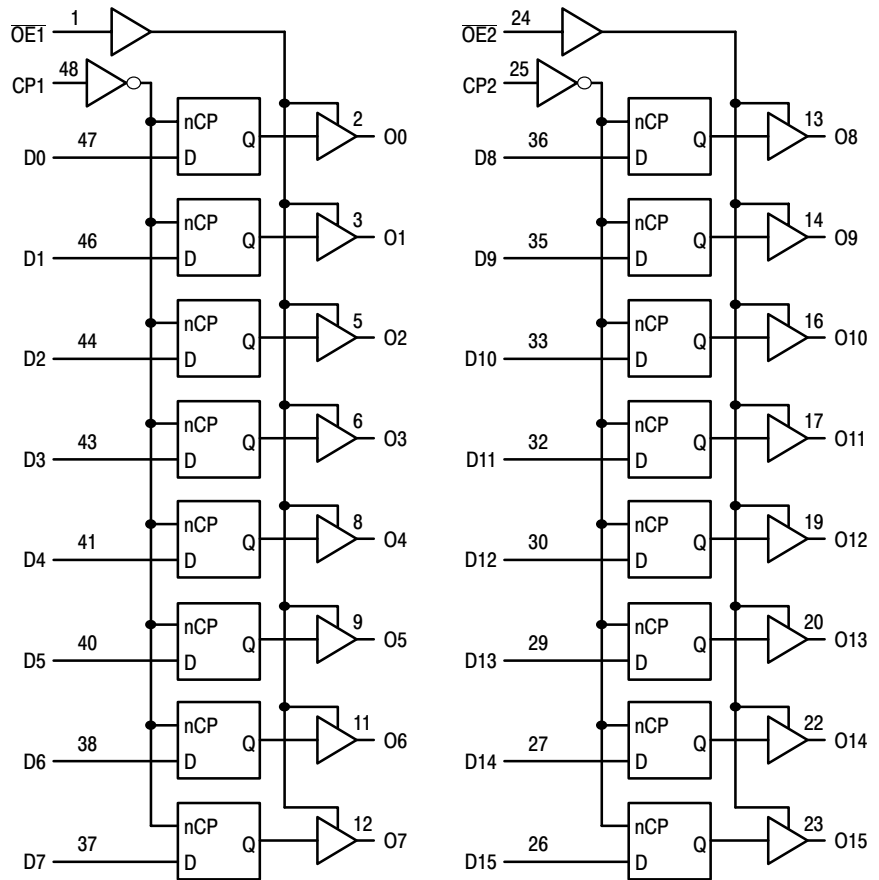


Figure 2. Logic Diagram

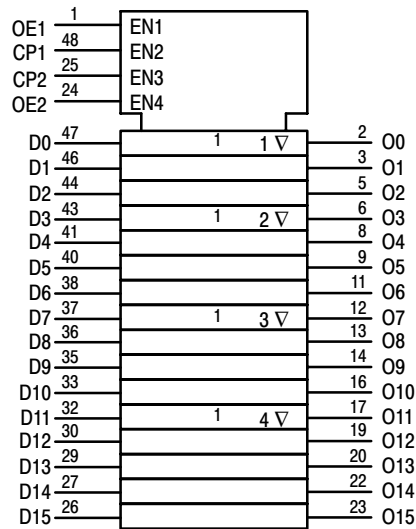


Figure 3. IEC Logic Diagram

Inputs			Outputs		Inputs			Outputs	
CP1	OE1	D0:7	O0:7		CP2	OE2	D8:15	O8:15	
↑	L	H	H		↑	L	H	H	
↑	L	L	L		↑	L	L	L	
X	L	X	O0		X	L	X	O0	
X	H	X	Z		X	H	X	Z	

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State; ↑ = Low-to-High Transition; X = High or Low Voltage Level and Transitions Are Acceptable, for I_{CC} reasons, DO NOT FLOAT Inputs. O0 = No Change.

MAXIMUM RATINGS (Note 1)

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage	− 0.5 to + 4.6	V
V _I	DC Input Voltage	− 0.5 to + 4.6	V
V _O	DC Output Voltage	− 0.5 to + 4.6	V
I _{IK}	DC Input Diode Current V _I < GND	− 50	mA
I _{OK}	DC Output Diode Current V _O < GND	− 50	mA
I _O	DC Output Sink Current	± 50	mA
I _{CC}	DC Supply Current per Supply Pin	± 100	mA
I _{GND}	DC Ground Current per Ground Pin	± 100	mA
T _{STG}	Storage Temperature Range	− 65 to + 150	°C
T _L	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
T _J	Junction Temperature Under Bias	+ 150	°C
θ _{JA}	Thermal Resistance (Note 2)	90	°C/W
MSL	Moisture Sensitivity	Level 1	
FR	Flammability Rating Oxygen Index: 30 to 35	UL 94 V-O @ 0.125 in	
V _{ESD}	ESD Withstand Voltage Human Body Model (Note 3) Machine Model (Note 4) Charged Device Model (Note 5)	> 2000 > 200 N/A	V
I _{LATCH-UP}	Latch-Up Performance Above V _{CC} and Below GND at 125°C (Note 6)	± 250	mA

Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum-rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

1. I_O absolute maximum rating must be observed.
2. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
3. Tested to EIA/JESD22-A114-A.
4. Tested to EIA/JESD22-A115-A.
5. Tested to JESD22-C101-A.
6. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	Supply Voltage Operating Data Retention Only	2.3 1.5	3.6 3.6	V
V _I	Input Voltage (Note 7)	−0.5	3.6	V
V _O	Output Voltage (Active State) (3-State)	0 0	3.6 3.6	V
T _A	Operating Free-Air Temperature	− 40	+ 85	°C
Δt/ΔV	Input Transition Rise or Fall Rate V _{CC} = 2.5 V ± 0.2 V V _{CC} = 3.0 V ± 0.3 V	0 0	20 10	ns/V

7. Unused inputs may not be left open. All inputs must be tied to a high-logic voltage level or a low-logic input voltage level.

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Condition	T _A = –40°C to +85°C		Unit
			Min	Max	
V _{IH}	HIGH Level Input Voltage (Note 8)	1.65 V ≤ V _{CC} < 2.3 V	0.65 × V _{CC}		V
		2.3 V ≤ V _{CC} ≤ 2.7 V	1.7		
		2.7 V < V _{CC} ≤ 3.6 V	2.0		
V _{IL}	LOW Level Input Voltage (Note 8)	1.65 V ≤ V _{CC} < 2.3 V		0.35 × V _{CC}	V
		2.3 V ≤ V _{CC} ≤ 2.7 V		0.7	
		2.7 V < V _{CC} ≤ 3.6 V		0.8	
V _{OH}	HIGH Level Output Voltage	1.65 V ≤ V _{CC} ≤ 3.6 V; I _{OH} = –100 μA	V _{CC} – 0.2		V
		V _{CC} = 1.65 V; I _{OH} = –4 mA	1.2		
		V _{CC} = 2.3 V; I _{OH} = –6 mA	2.0		
		V _{CC} = 2.3 V; I _{OH} = –12 mA	1.7		
		V _{CC} = 2.7 V; I _{OH} = –12 mA	2.2		
		V _{CC} = 3.0 V; I _{OH} = –12 mA	2.4		
		V _{CC} = 3.0 V; I _{OH} = –24 mA	2.0		
V _{OL}	LOW Level Output Voltage	1.65 V ≤ V _{CC} ≤ 3.6 V; I _{OL} = 100 μA		0.2	V
		V _{CC} = 1.65 V; I _{OL} = 4 mA		0.45	
		V _{CC} = 2.3 V; I _{OL} = 6 mA		0.4	
		V _{CC} = 2.3 V; I _{OL} = 12 mA		0.7	
		V _{CC} = 2.7 V; I _{OL} = 12 mA		0.4	
		V _{CC} = 3.0 V; I _{OL} = 24 mA		0.55	
I _I	Input Leakage Current	1.65 V ≤ V _{CC} ≤ 3.6 V; 0 V ≤ V _I ≤ 3.6 V		±5.0	μA
I _{I(HOLD)}	Minimum Bus–hold Input Current	V _{CC} = 3.6 V; V _{IN} = 0 to 3.6 V		±500	μA
		V _{CC} = 3.0 V, V _{IN} = 0.8 V	75		
		V _{CC} = 3.0 V, V _{IN} = 2.0 V	–75		
		V _{CC} = 2.3 V, V _{IN} = 0.7 V	45		
		V _{CC} = 2.3 V, V _{IN} = 1.7 V	–45		
		V _{CC} = 1.65 V, V _{IN} = 0.58 V	25		
		V _{CC} = 1.65 V, V _{IN} = 1.07 V	–25		
I _{OZ}	3–State Output Current	1.65 V ≤ V _{CC} ≤ 3.6 V; 0 V ≤ V _O ≤ 3.6 V; V _I = V _{IH} or V _{IL}		±10	μA
I _{OFF}	Power–Off Leakage Current	V _{CC} = 0 V; V _I or V _O = 3.6 V		10	μA
I _{CC}	Quiescent Supply Current (Note 9)	1.65 V ≤ V _{CC} ≤ 3.6 V; V _I = GND or V _{CC}		40	μA
		1.65 V ≤ V _{CC} ≤ 3.6 V; 3.6 V ≤ V _I , V _O ≤ 3.6 V		±40	
ΔI _{CC}	Increase in I _{CC} per Input	2.7 V < V _{CC} ≤ 3.6 V; V _{IH} = V _{CC} – 0.6 V		750	μA

8. These values of V_I are used to test DC electrical characteristics only.

9. Outputs disabled or 3–state only.

AC CHARACTERISTICS (Note 10; $t_R = t_F = 2.0$ ns; $C_L = 30$ pF; $R_L = 500$ Ω)

Symbol	Parameter	Wave- form	Limits						Unit
			T _A = −40°C to +85°C						
			V _{CC} = 3.0 V to 3.6 V		V _{CC} = 2.3 V to 2.7 V		V _{CC} = 1.65 V to 1.95 V		
			Min	Max	Min	Max	Min	Max	
f _{max}	Clock Pulse Frequency	1	250		200		100		MHz
t _{PLH} t _{PHL}	Propagation Delay CP to On	1	1.0 1.0	3.6 3.6	1.0 1.0	4.5 4.5	1.0 1.0	7.8 7.8	ns
t _{PZH} t _{PZL}	Output Enable Time to High and Low Level	2	1.0 1.0	4.7 4.7	1.0 1.0	6.0 6.0	1.0 1.0	9.2 9.2	ns
t _{PHZ} t _{PLZ}	Output Disable Time From High and Low Level	2	1.0 1.0	4.1 4.1	1.0 1.0	5.1 5.1	1.5 1.5	6.8 6.8	ns
t _s	Setup Time, High or Low Dn to CP	3	1.5		0.5		2.5		ns
t _h	Hold Time, High or Low Dn to CP	3	1.0		0.5		1.0		ns
t _w	CP Pulse Width, High	3	1.5		0.5		4.0		ns
t _{OSHL} t _{OSLH}	Output-to-Output Skew (Note 11)			0.5 0.5		0.5 0.5		0.75 0.75	ns

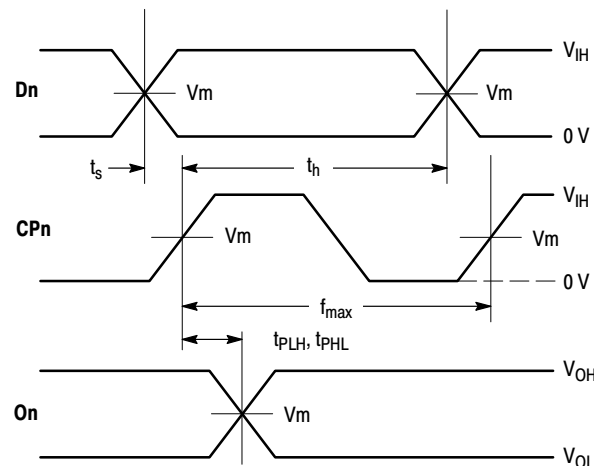
10. For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

11. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

CAPACITIVE CHARACTERISTICS

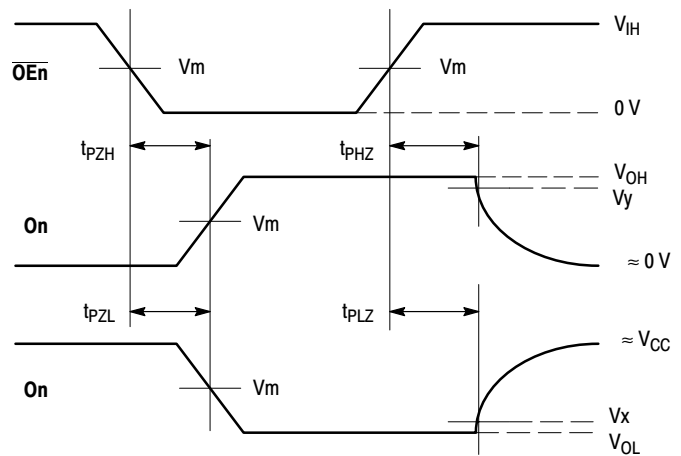
Symbol	Parameter	Condition	Typical	Unit
C_{IN}	Input Capacitance	Note 12	6	pF
C_{OUT}	Output Capacitance	Note 12	7	pF
C_{PD}	Power Dissipation Capacitance	Note 12, 10 MHz	20	pF

12. $V_{CC} = 1.8, 2.5$ or 3.3 V; $V_I = 0$ V or V_{CC} .



WAVEFORM 1 - PROPAGATION DELAYS, SETUP AND HOLD TIMES

$t_R = t_F = 2.0$ ns, 10% to 90%; $f = 1$ MHz; $t_W = 500$ ns

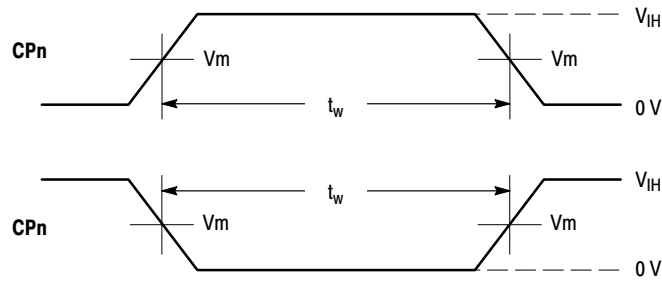


WAVEFORM 2 - OUTPUT ENABLE AND DISABLE TIMES

$t_R = t_F = 2.0$ ns, 10% to 90%; $f = 1$ MHz; $t_W = 500$ ns

Figure 4. AC Waveforms

74ALVCH16374

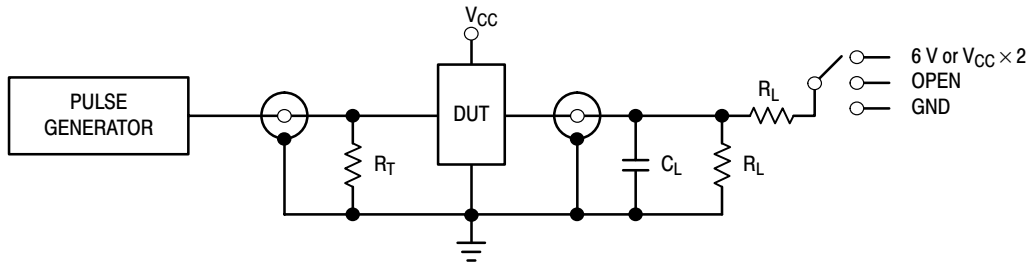


WAVEFORM 3 - PULSE WIDTH

$t_R = t_F = 2.0 \text{ ns}$ (or fast as required) from 10% to 90%

Figure 5. AC Waveforms

Symbol	V_{CC}		
	3.3 V ± 0.3 V	2.5 V ± 0.2 V	1.8 V ± 0.15 V
V_{IH}	2.7 V	V_{CC}	V_{CC}
V_m	1.5 V	$V_{CC}/2$	$V_{CC}/2$
V_x	$V_{OL} + 0.3 \text{ V}$	$V_{OL} + 0.15 \text{ V}$	$V_{OL} + 0.15 \text{ V}$
V_y	$V_{OH} - 0.3 \text{ V}$	$V_{OH} - 0.15 \text{ V}$	$V_{OH} - 0.15 \text{ V}$



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6 V at $V_{CC} = 3.3 \pm 0.3 \text{ V}$; $V_{CC} \times 2$ at $V_{CC} = 2.5 \pm 0.2 \text{ V}; 1.8 \text{ V} \pm 0.15 \text{ V}$
t_{PZH}, t_{PHZ}	GND

$C_L = 50 \text{ pF}$ for $V_{CC} = 3.0 \pm 0.3 \text{ V}$

$R_L = 500 \Omega$ or equivalent

$R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

Figure 6. Test Circuit

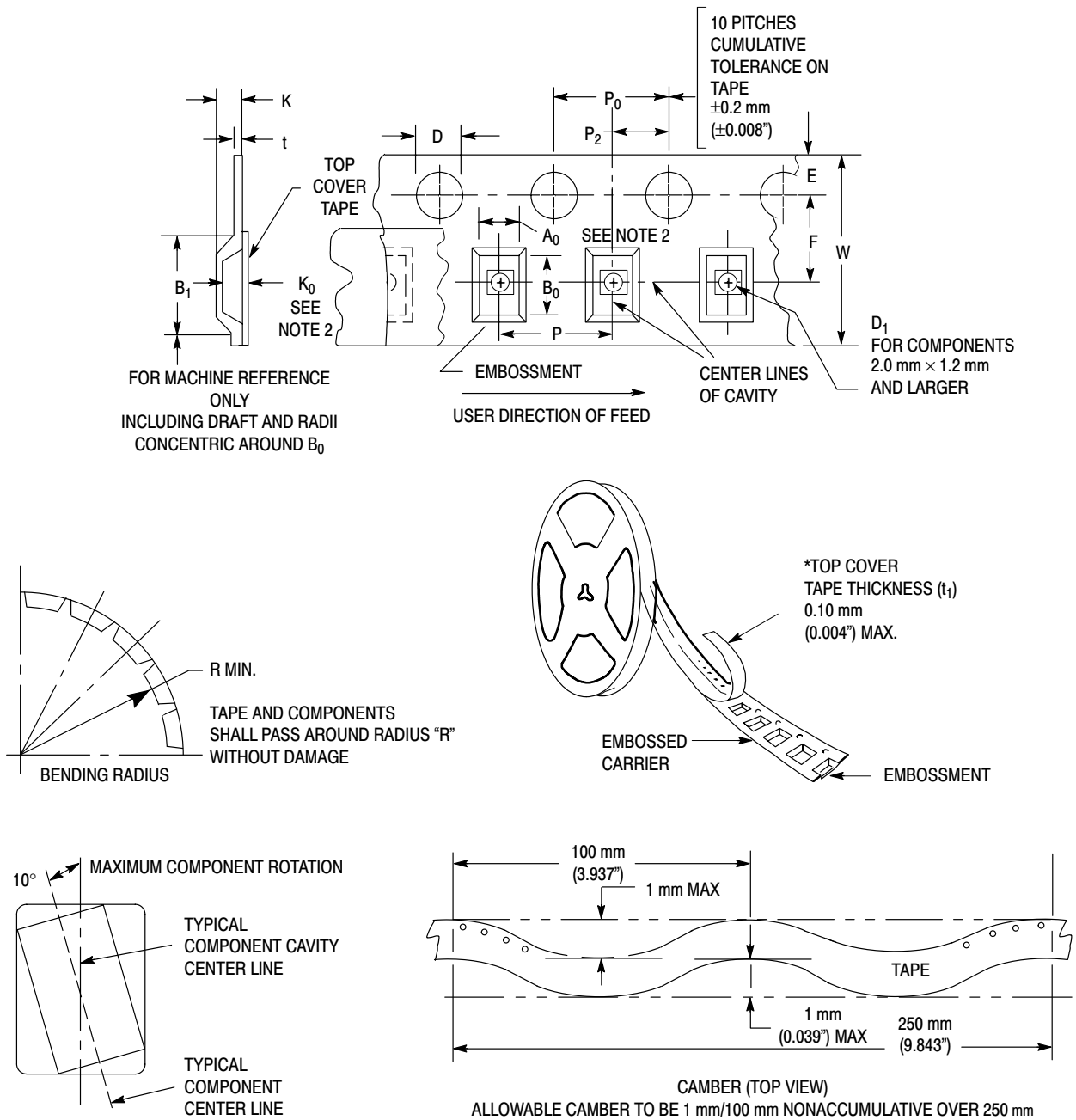


Figure 7. Carrier Tape Specifications

EMBOSSED CARRIER DIMENSIONS (See Notes 1 and 2)

Tape Size	B_1 Max	D	D_1	E	F	K	P	P_0	P_2	R	T	W
24mm	20.1mm (0.791")	1.5 + 0.1mm -0.0 (0.059 +0.004" -0.0)	1.5mm Min (0.060")	1.75 ± 0.1 mm (0.069 ± 0.004 ")	11.5 ± 0.10 mm (0.453 ± 0.004 ")	11.9 mm Max (0.468")	16.0 ± 0.1 mm (0.63 ± 0.004 ")	4.0 ± 0.1 mm (0.157 ± 0.004 ")	2.0 ± 0.1 mm (0.079 ± 0.004 ")	30 mm (1.18")	0.6 mm (0.024")	24.3 mm (0.957")

13. Metric Dimensions Govern—English are in parentheses for reference only.

14. A_0 , B_0 , and K_0 are determined by component size. The clearance between the components and the cavity must be within 0.05 mm min to 0.50 mm max. The component cannot rotate more than 10° within the determined cavity.

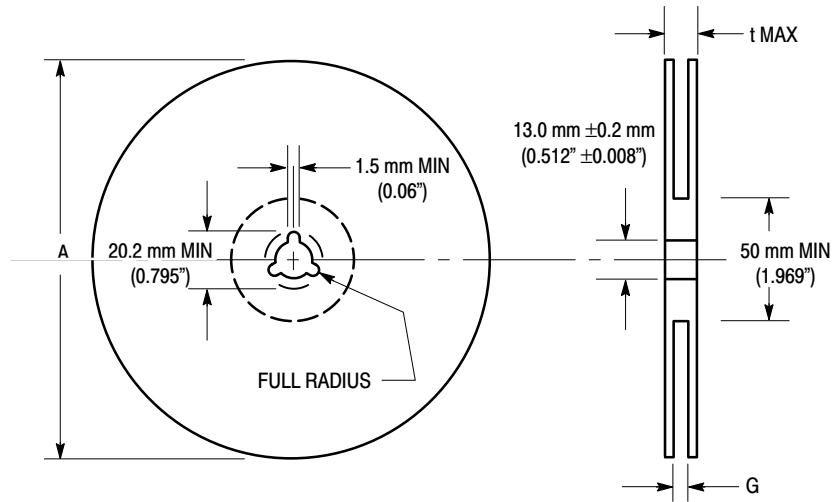


Figure 8. Reel Dimensions

REEL DIMENSIONS

Tape Size	A Max	G	t Max
24 mm	360 mm (14.173")	24.4 mm + 2.0 mm, -0.0 (0.961" + 0.078", -0.00)	30.4 mm (1.197")

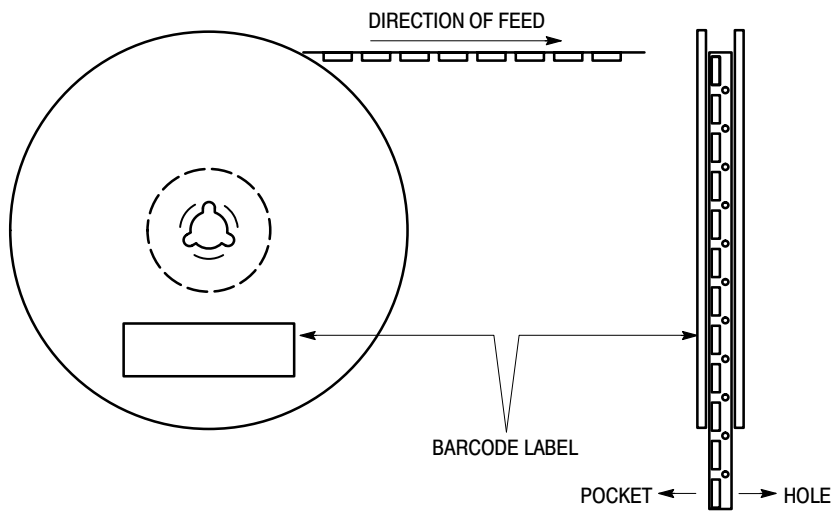


Figure 9. Reel Winding Direction

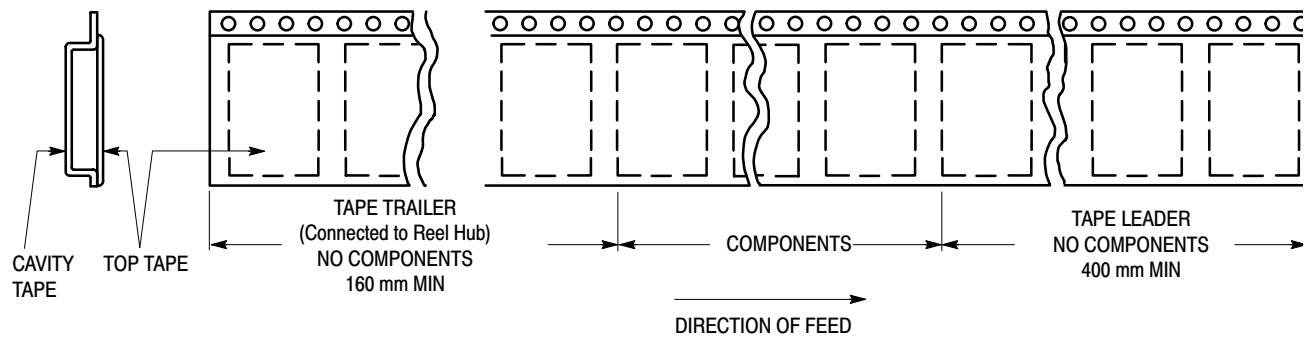


Figure 10. Tape Ends for Finished Goods

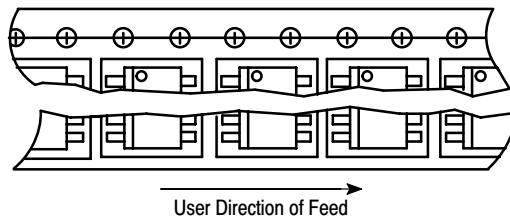


Figure 11. Reel Configuration

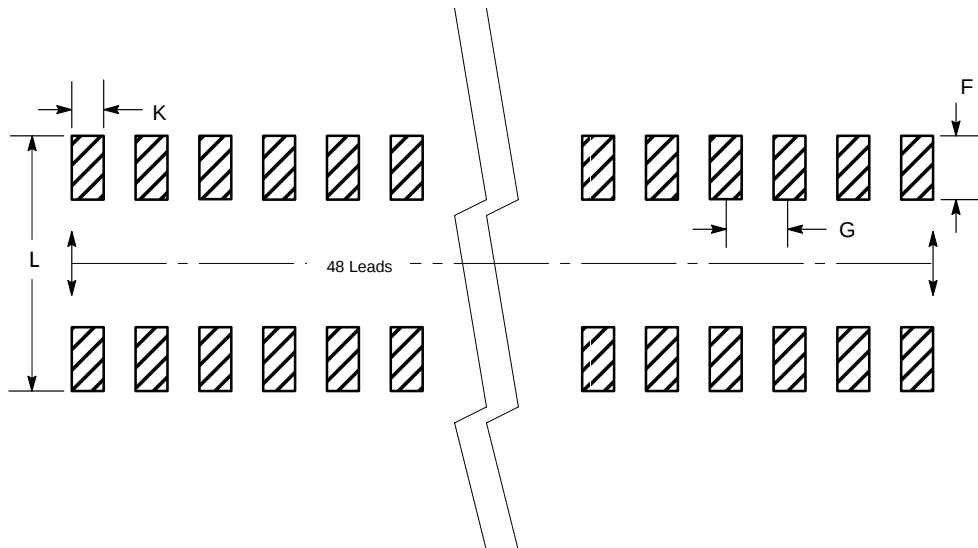
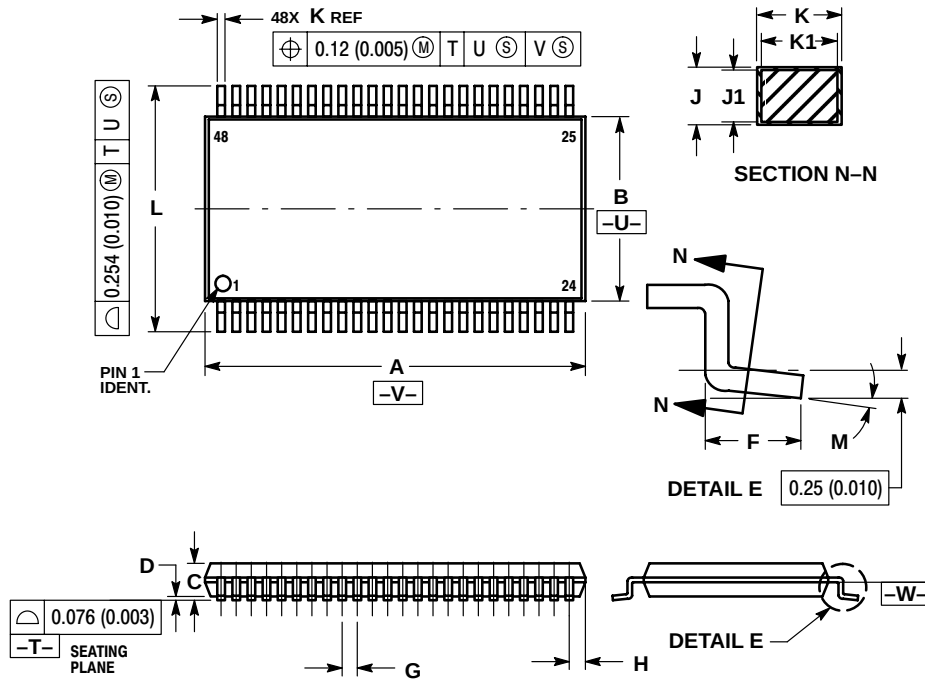


Figure 12. Package Footprint

PACKAGE DIMENSIONS

TSSOP
DT SUFFIX
CASE 1201-01
ISSUE A



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
6. DIMENSIONS A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	12.40	12.60	0.488	0.496
B	6.00	6.20	0.236	0.244
C	---	1.10	---	0.043
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.50 BSC		0.0197 BSC	
H	0.37	---	0.015	---
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.17	0.27	0.007	0.011
K1	0.17	0.23	0.007	0.009
L	7.95	8.25	0.313	0.325
M	0 °	8 °	0 °	8 °

Notes

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